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April 1st, 2010 Renesas Electronics Corporation

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DATA SHEET



MOS FIELD EFFECT TRANSISTOR **2SK2413**

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK2413 is N-Channel MOS Field Effect Transistor designed for high speed switching applications.

FEATURES

Low On-Resistance

RDS(on)1 = 70 m Ω MAX. (@ VGS = 10 V, ID = 5.0 A) RDS(on)2 = 95 m Ω MAX. (@ VGS = 4 V, ID = 5.0 A)

- Low Ciss Ciss = 860 pF TYP.
- Built-in G-S Gate Protection Diodes
- High Avalanche Capability Ratings

QUALITY GRADE

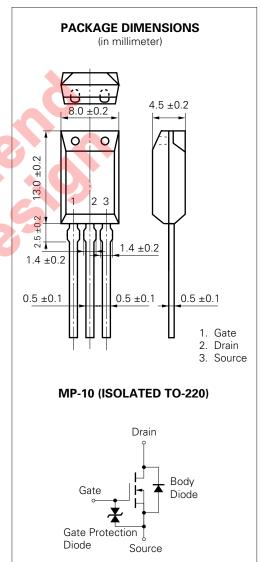
Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	Vdss	60	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	D(DC)	±10	А
Drain Current (pulse)*	D(pulse)	±40	А
Total Power Dissipation ($T_A = 25$ °C)	Рт	1.8	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current**	las	10	А
Single Avalanche Energy**	Eas	10	mJ
* PW \leq 10 μ s, Duty Cycle \leq 1 %			
	66. 1/	-	

** Starting T_ch = 25 °C, R_G = 25 $\Omega,$ V_Gs = 20 V \rightarrow 0

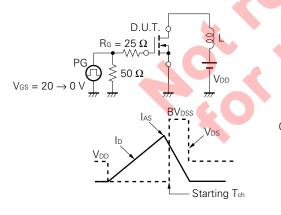


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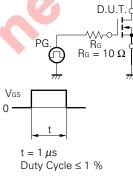
ELECTRICAL	CHARACTERISTICS	(TA = 25 °C)
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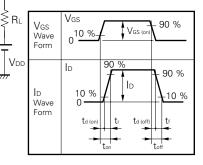
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS(on)1		50	70	mΩ	$V_{GS} = 10 \text{ V}, \text{ Id} = 5.0 \text{ A}$
Drain to Source On-Resistance	RDS(on)2		70	95	mΩ	$V_{GS} = 4 V, I_{D} = 5.0 A$
Gate to Source Cutoff Voltage	V _{GS(off)}	1.0	1.6	2.0	V	$V_{DS} = 10 V$, $I_D = 1 mA$
Forward Transfer Admittance	y _{fs}	7.0	12		S	$V_{DS} = 10 V, I_{D} = 5.0 A$
Drain Leakage Current	IDSS			±10	μA	$V_{DS} = 60 V, V_{GS} = 0$
Gate to Source Leakage Current	Igss			±10	μA	$V_{GS} = \pm 20 V$, $V_{DS} = 0$
Input Capacitance	Ciss		860		pF	$V_{DS} = 10 V$
Output Capacitance	Coss		440		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		110		pF	f = 1 MHz
Turn-On Delay Time	td(on)		15		ns	ID = 5.0 A
Rise Time	tr		90		ns	$V_{GS(on)} = 10 V$
Turn-Off Delay Time	td(off)		75		ns	$V_{DD} = 30 V$
Fall Time	tr		30		ns	$R_G = 10 \Omega$
Total Gate Charge	Q _G		24		nC	$J_D = 20 A$
Gate to Source Charge	Q _{GS}		3.0		nC	V _{DD} = 48 V
Gate to Drain Charge	Qgd		6.0		nC	V _{GS} = 10 V
Body Diode Forward Voltage	VF(S-D)		1.0		V	IF = 10 A, VGS = 0
Reverse Recovery Time	trr		95	16	ns	IF = 10 A, VGS = 0
Reverse Recovery Charge	Qrr		250		nC	di/dt = 100 A/µs

Test Circuit 1 Avalanche Capability

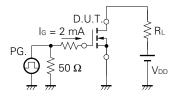


Test Circuit 2 Switching Time



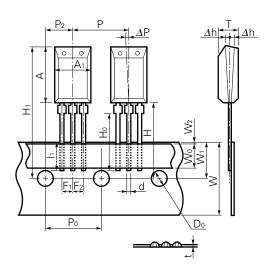


Test Circuit 3 Gate Charge



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

Radial Tape Specification

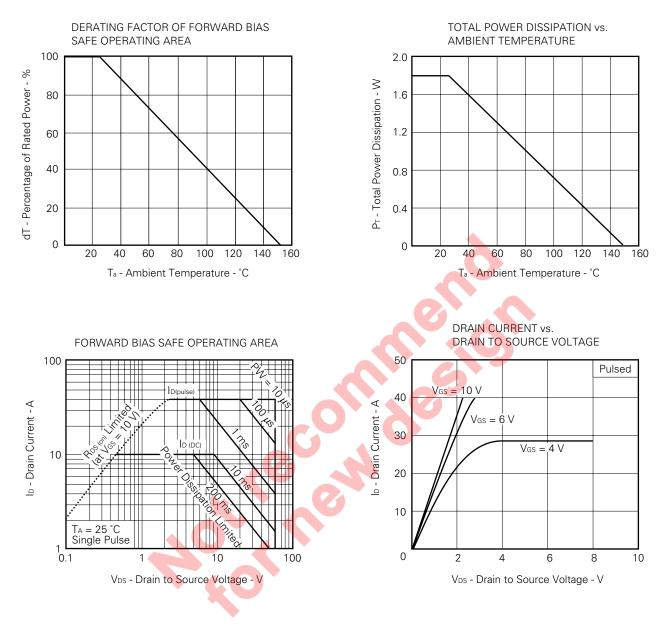


Dimension (unit: mm)

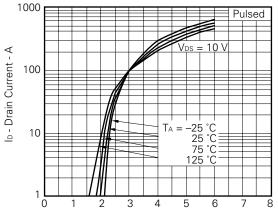
_	ltem		
$\frac{P}{\Delta P}$ $\Delta h = \frac{T}{\Delta h}$	Component Body Length along Tape	A ₁	8.0 ± 0.2
	. , , , , , , , , , , , , , , , , , , ,		
	Component Body Height	A	13.0 ± 0.2
	Component Body Width	Т	4.5 ± 0.2
	Component Lead Width Dimension	d	0.5 ± 0.1
	Lead Wire Enclosure	I1	2.5 MIN.
	Component Center Pitch	Р	12.7 ± 1.0
	Feedhole Pitch	Po	12.7 ± 0.3
	Feedhole Center to Center Lead	P ₂	6.35 ± 0.5
	Component Lead Pitch	F 1, F 2	2.5 +0.4 -0.1
	Deflection Front or Rear	∆h	±1.0
Î	Deflection Left or Right	ΔP	±1.3
	Carrier Strip Width	W	18.0 ^{+1.0} -0.5
	Adhesive Tape Width	Wo	5.0 MIN.
	Feedhole Location	W ₁	9.0 ± 0.5
	Adhesive Tape Position	W2	0.7 MIN.
	Height of Seating Plane	H₀	16.0 ± 0.5
	Feedhole to upper of Component	H1	32.2 MAX.
	Feedhole to Bottom of Component	Н	20.0 MAX.
	Tape Feedhole Diameter	Do	4.0 ± 0.2
	Overall Taped Package Thickness	t	0.7 ± 0.2

NEC

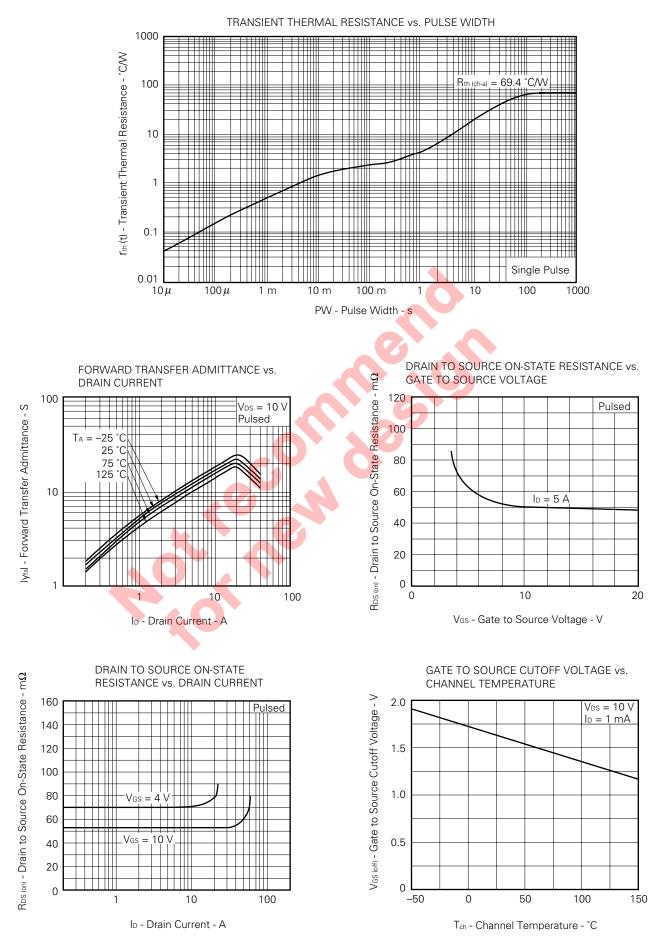
TYPICAL CHARACTERISTICS (TA = 25 °C)



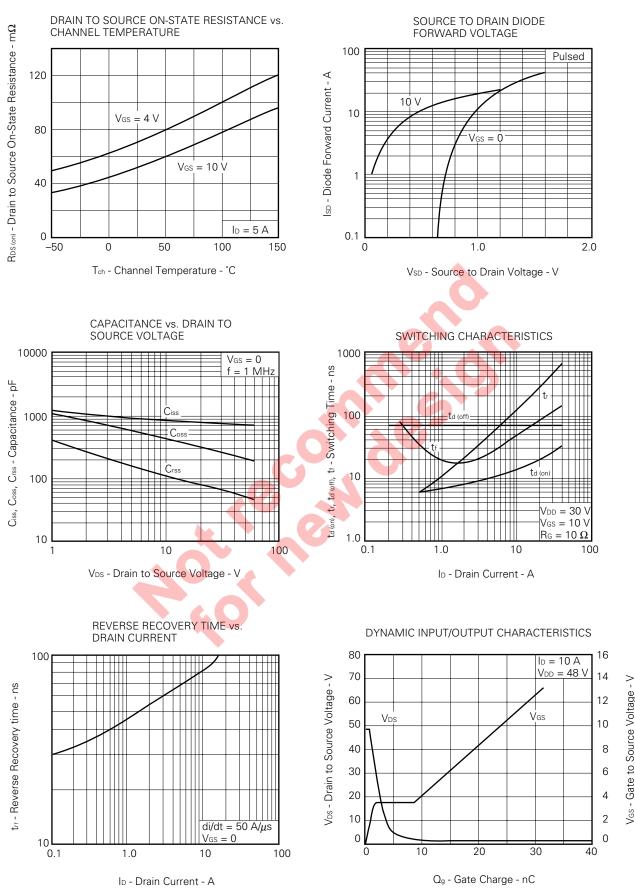




V_{GS} - Gate to Source Voltage - V

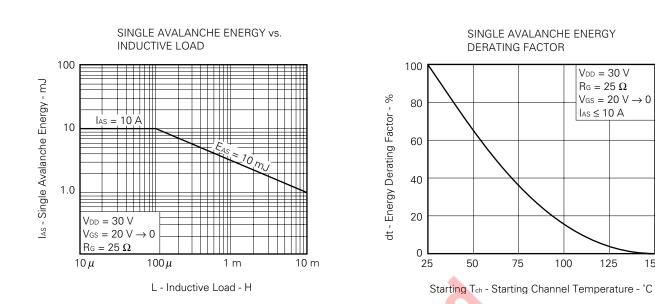






125

150



REFERENCE

NEC

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

[MEMO]



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